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TL061

Low power JFET single operational amplifiers

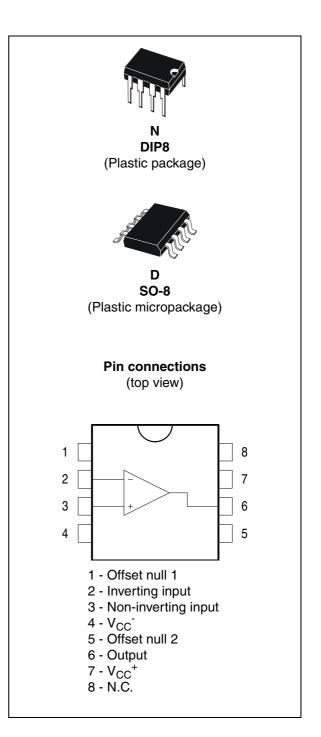
Features

- Very low power consumption: 200 µA
- Wide common-mode (up to V_{CC}⁺) and differential voltage ranges
- Low input bias and offset currents
- Output short-circuit protection
- High input impedance JFET input stage
- Internal frequency compensation
- Latch-up free operation
- High slew rate: 3.5 V/µs

Description

The TL061 is a high-speed JFET input single operational amplifier, that incorporates wellmatched, high-voltage JFET and bipolar transistors in a monolithic integrated circuit.

The device features high slew rates, low input bias and offset currents, and low offset voltage temperature coefficient.



1 Schematic diagram

Figure 1. Schematic diagram

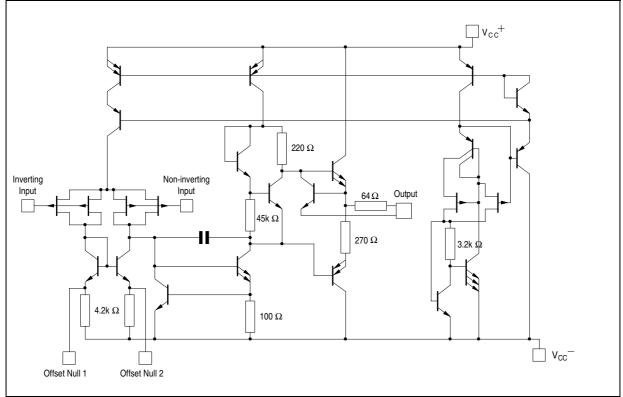
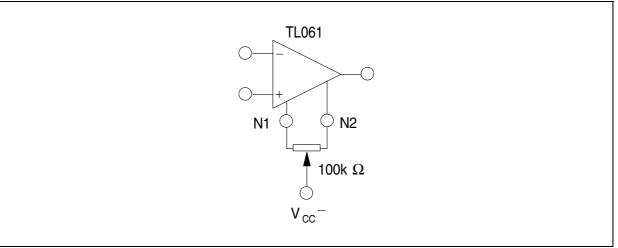


Figure 2. Input offset voltage null circuit





2 Absolute maximum ratings and operating conditions

Symbol	Parameter		Value		Unit	
Symbol	Parameter	TL061M, AM, BM	TL061I, AI, BI	TL061C, AC, BC	Unit	
V _{CC}	Supply voltage ⁽¹⁾	±18				
Vi	Input voltage ⁽²⁾		±15		V	
V _{id}	Differential input voltage ⁽³⁾		±30		V	
P _{tot}	Power dissipation		680		mW	
	Output short-circuit duration (4)	Infinite				
T _{stg}	Storage temperature range	-65 to +150	-65 to +150	-65 to +150	°C	
R _{thja}	Thermal resistance junction to ambient ^{(5) (6)} SO-8 DIP8		125 85		°C/W	
R _{thjc}	Thermal resistance junction to case ^{(5) (6)} SO-8 DIP8	40 41				
	HBM: human body model ⁽⁷⁾	800				
ESD	MM: machine model ⁽⁸⁾	200				
	CDM: charged device model ⁽⁹⁾		1.5		kV	

Table 1. Absolute maximum ratings

1. All voltage values, except differential voltage, are with respect to the zero reference level (ground) of the supply voltages where the zero reference level is the midpoint between V_{CC}^+ and V_{CC}^- .

2. The magnitude of the input voltage must never exceed the magnitude of the supply voltage or 15 volts, whichever is less.

3. Differential voltages are the non-inverting input terminal with respect to the inverting input terminal.

4. The output may be shorted to ground or to either supply. Temperature and/or supply voltages must be limited to ensure that the dissipation rating is not exceeded.

5. Short-circuits can cause excessive heating and destructive dissipation.

6. Rth are typical values.

7. Human body model: 100 pF discharged through a 1.5 k Ω resistor between two pins of the device, done for all couples of pin combinations with other pins floating.

8. Machine model: a 200 pF cap is charged to the specified voltage, then discharged directly between two pins of the device with no external series resistor (internal resistor < 5 Ω), done for all couples of pin combinations with other pins floating.

9. Charged device model: all pins plus package are charged together to the specified voltage and then discharged directly to the ground.

Table 2. Operating conditions

Symbol	Parameter	TL061M, AM, BM	TL061I, AI, BI	TL061C, AC, BC	Unit
V _{CC}	Supply voltage range		6 to 36		V
T _{oper}	Operating free-air temperature range	-55 to +125	-40 to +105	0 to +70	°C



3 Electrical characteristics

o	D	٢	L061N	Λ		TL061		TL061C			11
Symbol	Parameter		Тур.	Max.	Min.	Тур.	Max.	Min.	Тур.	Max.	Unit
V _{io}	Input offset voltage ($R_S = 50\Omega$) $T_{amb} = +25^{\circ}C$ $T_{min} \le T_{amb} \le T_{max}$		3	6 9		3	6 9		3	15 20	mV
DV_{io}	Temperature coefficient of input offset voltage ($R_S = 50\Omega$)		10			10			10		μV/°C
I _{io}	Input offset current ⁽¹⁾ $T_{amb} = +25^{\circ}C$ $T_{min} \le T_{amb} \le T_{max}$		5	100 20		5	100 10		5	200 5	pA nA
I _{ib}	Input bias current ⁽¹⁾ $T_{amb} = +25^{\circ}C$ $T_{min} \le T_{amb} \le T_{max}$		30	200 20		30	200 20		30	400 10	pA nA
V _{icm}	Input common mode voltage range	±11.5	+15 -12		±11.5	+15 -12		±11	+15 -12		v
V _{opp}	Output voltage swing ($R_L = 10k\Omega$) $T_{amb} = +25^{\circ}C$ $T_{min} \le T_{amb} \le T_{max}$	20 20	27		20 20	27		20 20	27		V
A _{vd}	$ \begin{array}{l} \mbox{Large signal voltage gain} \\ R_L = 10 k \Omega, V_o = \pm 10 V, \\ T_{amb} = +25^\circ C \\ T_{min} \leq T_{amb} \leq T_{max} \end{array} $	4 4	6		4 4	6		3 3	6		V/mV
GBP	Gain bandwidth product T_{amb} = +25°C, R _L =10k Ω , C _L =100pF		1			1			1		MHz
R _i	Input resistance		10 ¹²			10 ¹²			10 ¹²		Ω
CMR	Common mode rejection ratio $R_S = 50\Omega$	80	86		80	86		70	76		dB
SVR	Supply voltage rejection ratio $R_S = 50\Omega$	80	95		80	95		70	95		dB
I _{CC}	Supply current, no load T _{amb} = +25°C, no load, no signal		200	250		200	250		200	250	μA
P _D	Total power consumption $T_{amb} = +25^{\circ}C$, no load, no signal		6	7.5		6	7.5		6	7.5	mW
SR	Slew rate V_i = 10V, R_L = 10k Ω , C_L = 100pF, A_v =1	1.5	3.5		1.5	3.5		1.5	3.5		V/µs
t _r	Rise time V_i = 20mV, R _L =10k Ω , C _L =100pF, A _v =1		0.2			0.2			0.2		μs

Table 3.	$V_{CC} = \pm 15 V, T_{amb} = \pm 25^{\circ}$	° C (unless otherwise specified)
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Symbol	nbol Parameter		TL061M		TL061I			TL061C			Unit
Symbol	Parameter	Min.	Тур.	Max.	Min.	Тур.	Max.	Min.	Тур.	Max.	Unit
K _{ov}	Overshoot factor (see <i>Figure 16</i>) V_i = 20mV, R_L = 10k Ω C_L =100pF, A_v =1		10			10			10		%
e _n	Equivalent input noise voltage $R_S = 100 \Omega$, f = 1kHz		42			42			42		<u>nV</u> √Hz

Table 3. $V_{CC} = \pm 15 \text{ V}, T_{amb} = \pm 25^{\circ} \text{ C}$ (unless otherwise specified) (continued)

1. The input bias currents of a FET-input operational amplifier are normal junction reverse currents, which are temperature sensitive. Pulse techniques must be used that will maintain the junction temperature as close to the ambient temperature as possible.

Table 4.	V _{CC} = ±15 V, T _{amb} = +25° C (unless otherwise	specified)

Symbol	ol Parameter –		51AC, A	I, AM	TL061BC, BI, BM			Unit
Symbol	Parameter	Min.	Тур.	Max.	Min.	Тур.	Max.	Unit
V _{io}	Input offset voltage ($R_S = 50\Omega$) $T_{amb} = +25^{\circ}C$ $T_{min} \leq T_{amb} \leq T_{max}$		3	6 7.5		2	3 5	mV
DV _{io}	Temperature coefficient of input offset voltage $(R_S = 50\Omega)$		10			10		μV/°C
l _{io}	Input offset current ⁽¹⁾ $T_{amb} = +25^{\circ}C$ $T_{min} \le T_{amb} \le T_{max}$		5	100 3		5	100 3	pA nA
l _{ib}	Input bias current ⁽¹⁾ $T_{amb} = +25^{\circ}C$ $T_{min} \leq T_{amb} \leq T_{max}$		30	200 7		30	200 7	pA nA
V _{icm}	Input common mode voltage range	±11.5	+15 -12		±11	+15 -12		V
V _{opp}	Output voltage swing (R _L = 10k Ω) T _{amb} = +25°C T _{min} \leq T _{amb} \leq T _{max}	20 20	27		20 20	27		v
A _{vd}	Large signal voltage gain ($R_L = 10k\Omega$, $V_o = \pm 10V$) $T_{amb} = +25^{\circ}C$ $T_{min} \le T_{amb} \le T_{max}$	4 4	6		4 4	6		V/mV
GBP	Gain bandwidth product T _{amb} = +25°C, R _L =10k Ω , C _L = 100pF		1			1		MHz
R _i	Input resistance		10 ¹²			10 ¹²		Ω
CMR	Common mode rejection ratio ($R_S = 50\Omega$)	80	86		80	86		dB
SVR	Supply voltage rejection ratio ($R_S = 50\Omega$)	80	95		80	95		dB
I _{CC}	Supply current, no load T _{amb} = +25°C, no load, no signal		200	250		200	250	μA
P _D	Total power consumption T _{amb} = +25°C, no load, no signal		6	7.5		6	7.5	mW



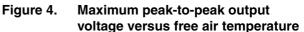
Symbol	Parameter		TL061AC, AI, AM			TL061BC, BI, BM		
Symbol	Falainetei	Min.	Тур.	Max.	Min.	Тур.	Max.	Unit
SR	Slew rate $V_i = 10V$, $R_L = 10k\Omega$, $C_L = 100pF$, $A_v = 1$	1.5	3.5		1.5	3.5		V/µs
t _r	Rise time $V_i = 20mV$, $R_L = 10k\Omega$, $C_L = 100pF$, $A_v = 1$		0.2			0.2		μs
K _{ov}	Overshoot factor (see <i>Figure 16</i>) $V_i = 20mV$, $R_L = 10k\Omega$, $C_L = 100pF$, $A_v = 1$		10			10		%
e _n	Equivalent input noise voltage R _S = 100Ω, f = 1KHz		42			42		<u>nV</u> √Hz

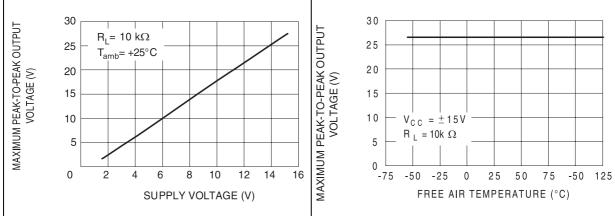
Table 4. $V_{CC} = \pm 15 \text{ V}, T_{amb} = \pm 25^{\circ} \text{ C}$ (unless otherwise specified) (continued)

1. The input bias currents of a FET-input operational amplifier are normal junction reverse currents, which are temperature sensitive. Pulse techniques must be used that will maintain the junction temperature as close to the ambient temperature as possible



Figure 3. Maximum peak-to-peak output Figure 3. Voltage versus supply voltage





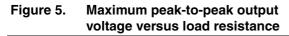


Figure 6. Maximum peak-to-peak output voltage versus frequency

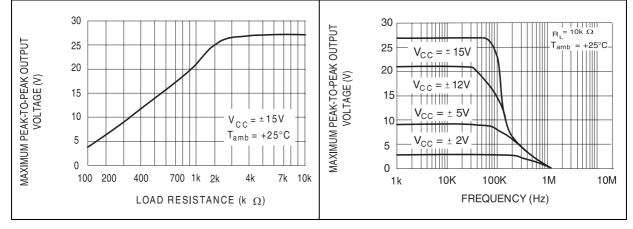
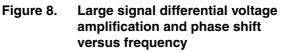
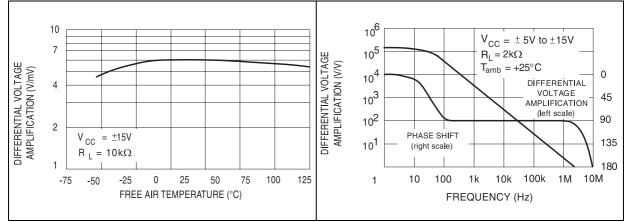


Figure 7. Differential voltage amplification versus free air temperature





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Figure 9. Supply current per amplifier versus Figure 10. Supply current per amplifier versus free air temperature

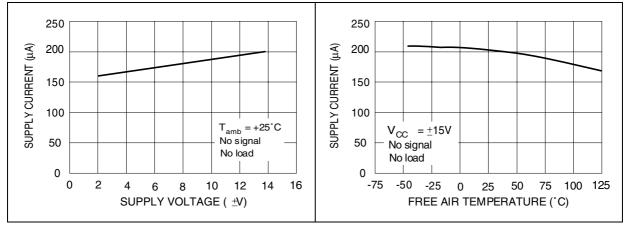
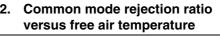


Figure 11. Total power dissipated versus free Figure 12. air temperature



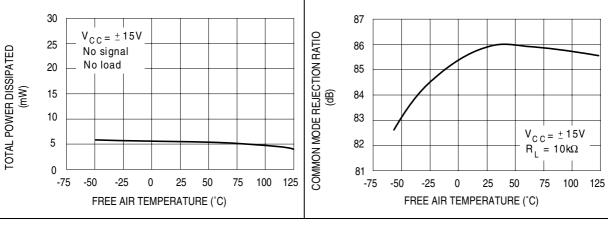
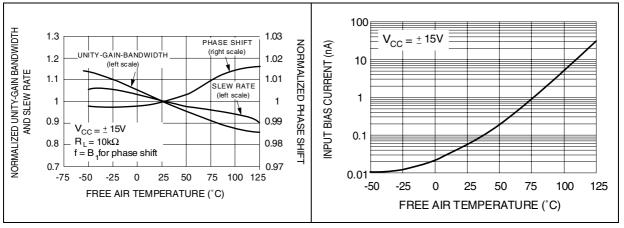


Figure 13. Normalized unity gain bandwidth slew rate, and phase shift versus temperature

Figure 14. Input bias current versus free air temperature



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 $V_{\rm CC} = \pm 15V$

 $R_{L} = 10k \Omega$

1

0.8

 $T_{amb} = +25^{\circ}C$

12

14

Figure 15. Voltage follower large signal pulse Figure 16. Output voltage versus elapsed time response

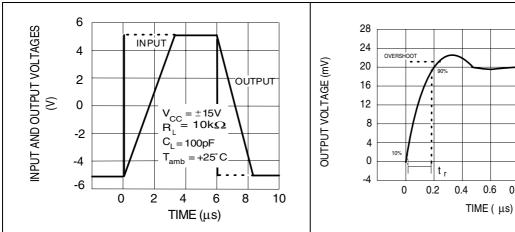
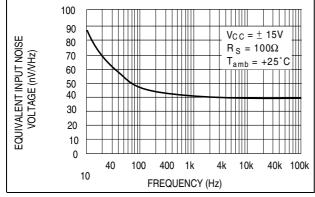
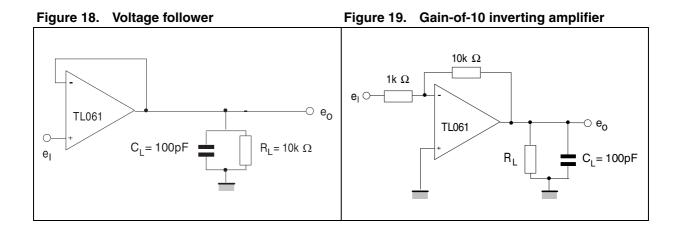


Figure 17. Equivalent input noise voltage versus frequency





4 Parameter measurement information



5 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: www.st.com. ECOPACK[®] is an ST trademark.



5.1 DIP8 package information

Figure 20. DIP8 package mechanical drawing

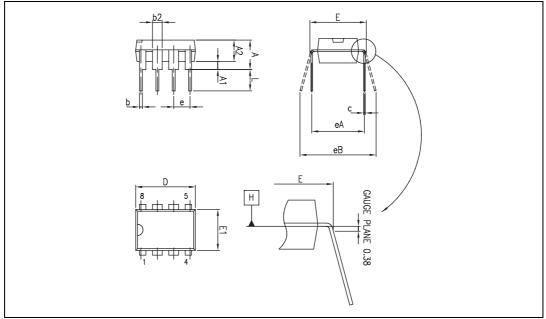


Table 5.DIP8 package mechanical data

			Dime	nsions				
Ref.	Millimeters				Inches			
	Min.	Тур.	Max.	Min.	Тур.	Max.		
А			5.33			0.210		
A1	0.38			0.015				
A2	2.92	3.30	4.95	0.115	0.130	0.195		
b	0.36	0.46	0.56	0.014	0.018	0.022		
b2	1.14	1.52	1.78	0.045	0.060	0.070		
с	0.20	0.25	0.36	0.008	0.010	0.014		
D	9.02	9.27	10.16	0.355	0.365	0.400		
E	7.62	7.87	8.26	0.300	0.310	0.325		
E1	6.10	6.35	7.11	0.240	0.250	0.280		
е		2.54			0.100			
eA		7.62			0.300			
eB			10.92			0.430		
L	2.92	3.30	3.81	0.115	0.130	0.150		

5.2 SO-8 package information



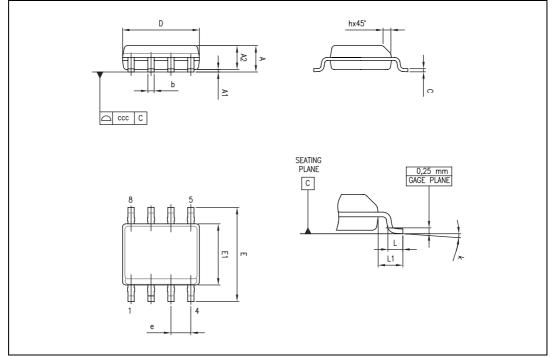


Table 6.	SO-8 package m	echanical data
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	Dimensions								
Ref.	Millimeters				Inches				
	Min.	Тур.	Max.	Min.	Тур.	Max.			
А			1.75			0.069			
A1	0.10		0.25	0.004		0.010			
A2	1.25			0.049					
b	0.28		0.48	0.011		0.019			
с	0.17		0.23	0.007		0.010			
D	4.80	4.90	5.00	0.189	0.193	0.197			
E	5.80	6.00	6.20	0.228	0.236	0.244			
E1	3.80	3.90	4.00	0.150	0.154	0.157			
е		1.27			0.050				
h	0.25		0.50	0.010		0.020			
L	0.40		1.27	0.016		0.050			
L1		1.04			0.040				
k	0		8 °	1 °		8°			
ССС			0.10			0.004			



6 Ordering information

Part number	Temperature range	Package	Packing	Marking
TL061MN TL061AMN TL061BMN	-55°C, +125°C	DIP8	Tube	TL061MN TL061AMN TL061BMN
TL061MD/MDT TL061AMD/MDT TL061BMD/BMDT		SO-8	Tube or tape & reel	061M 061AM 061BM
TL061IN TL061AIN TL061BIN	-40°C, +105°C	DIP8	Tube	TL061IN TL061AIN TL061BIN
TL061ID/IDT TL061AID/AIDT TL061BID/BIDT		SO-8	Tube or tape & reel	061I 061AI 061BI
TL061CN TL061ACN TL061BCN	0°070°0	DIP8	Tube	TL061CN TL061ACN TL061BCN
TL061CD/CDT TL061ACD/ACDT TL061BCD/BCDT	0°C, +70°C	SO-8	Tube or tape & reel	061C 061AC 061BC



7 Revision history

evision history
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Date	Revision	Changes
13-Nov-2001	1	Initial release.
27-Jul-2007	2	Added values for R _{thja} and R _{thjc} in <i>Table 1: Absolute maximum ratings</i> . Added <i>Table 2: Operating conditions</i> . Updated format.
05-Mar-2009	3	Updated package mechanical drawings and data in <i>Chapter 5: Package information</i> .



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